RT3THHM

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

DESCRIPTION

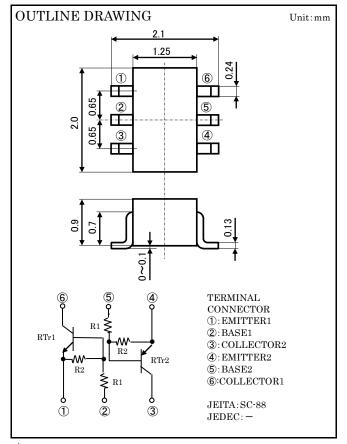
RT3THHM is composite transistor built with RT1N436 chip and RT1P436 chip in SC-88 package.

FEATURE

Built-in bias resistor (R1=4.7k Ω , R2=47k Ω) Mini package for easy mounting

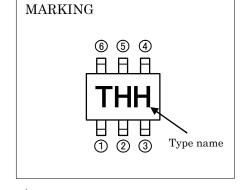
APPLICATION

Inverted circuit, Switching circuit, Interface circuit, Driver circuit



MAXIMUM RATING (Ta=25°C) (RTr1_NPN, RTr2_PNP)

SYMBOL	PARAMETER	RATING	UNIT	
Vcbo	Collector to Base voltage	50	V	
Vebo	Emitter to Base voltage	6	V	
VCEO	Collector to Emitter voltage	50	V	
Vin	Input voltage	30	V	
$I_{\mathbf{C}}$	Collector current	100	mA	
Icm	Peak Collector current	200	mA	
P_{T}	Total dissipation	200	mW	
Tj	Junction temperature	+150	°C	
T_{stg}	Storage temperature	-55~+150	°C	



 $\prescript{\text{MPNP built in transistor}}$ of "—"sign is abbreviation.

ELECTRICAL CHARACTERISTICS (Ta=25°C) (RTr1_NPN, RTr2_PNP)

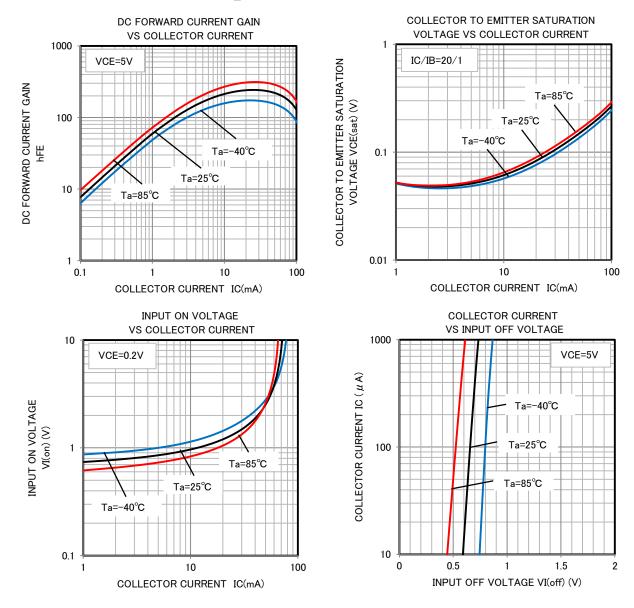
Symbol	Parameter	Test conditions		Limits			TT :
				Min	Тур	Max	Unit
V(BR)CEO	Collector to Emitter breakdown voltage	$I_{\rm C} = 100 \mu{\rm A}, {\rm R}_{\rm BE} = \infty$		50	_	-	V
Icbo	Collector cut off current V _{CB} =50V, I _E =0		_	_	0.1	μΑ	
IEBO	Smitter cut off current V_{EB} =5V, I_{C} =0		73	97	140	μΑ	
$_{ m hFE}$	DC forward current gain	$V_{CE}=5V$, $I_{C}=10mA$		80	_	_	_
V _{CE} (sat)	Collector to Emitter saturation voltage Ic=10mA, I _B =0.5mA		-	_	0.3	V	
VI(ON)	Input on voltage V_{CE} =0.2V, I_{C} =5mA		1	0.8	1.4	V	
V _{I(OFF)}	Input off voltage	$V_{CE}=5V$, $I_{C}=100 \mu A$		0.4	0.6	_	V
R_1	Input resistor	_		3.3	4.7	6.1	$k\Omega$
R_2/R_1	Resistor ratio	_		8	10	12	_
$ m f_T$	Gain band width product	V _{CE} =6V, I _E =10mA	RTr1	_	200	_	m MHz
			RTr2	1	150	_	MHZ

XPNP built in transistor of "−"sign is abbreviation.

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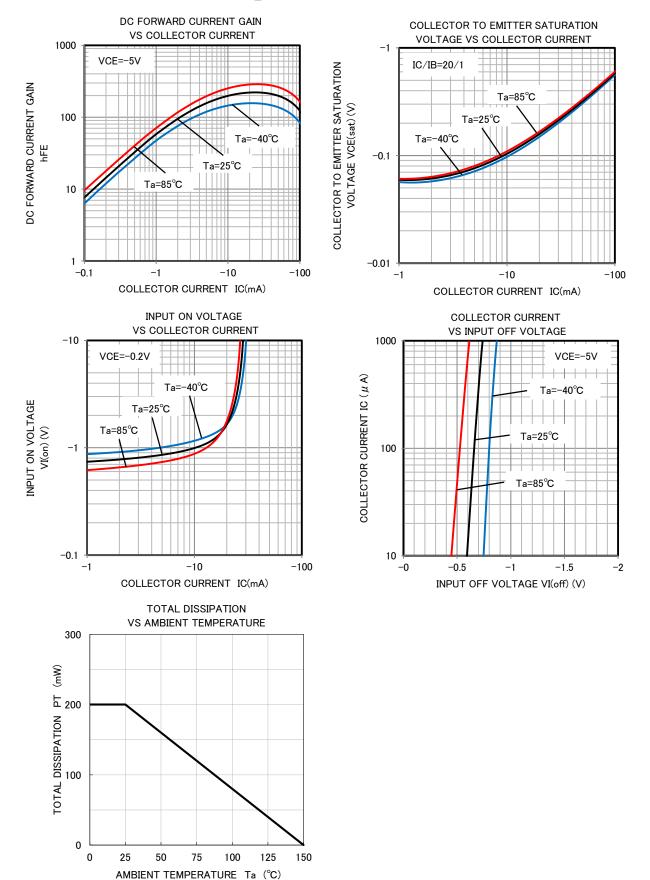
TYPICAL CHARACTERISTICS (RTr1_NPN)



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TYPICAL CHARACTERISTICS (RTr 2_PNP)



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